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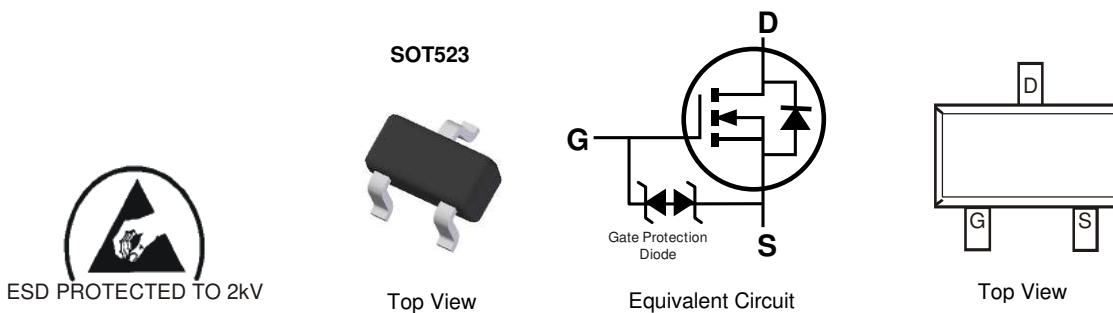
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- ESD Protected Gate to 2kV
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)



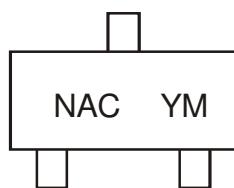
Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMN55D0UT -7	Commercial	SOT523	3,000/Tape & Reel
DMN55D0UTQ -7	Automotive	SOT523	3,000/Tape & Reel

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q10x qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



NAC = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: U = 2007)
 M = Month (ex: 9 = September)

Date Code Key

Year	2007	---	2015	2016	2017	2018	2019	2020	2021	2022	2023	
Code	U	---	C	D	E	F	G	H	I	J	K	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V_{DSS}	50	V
Gate-Source Voltage	V_{GSS}	± 12	V
Drain Current (Note 6) Continuous	I_D	160	mA
Pulsed Drain Current (Note 6)	I_{DM}	560	mA

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	P_D	200	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	625	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

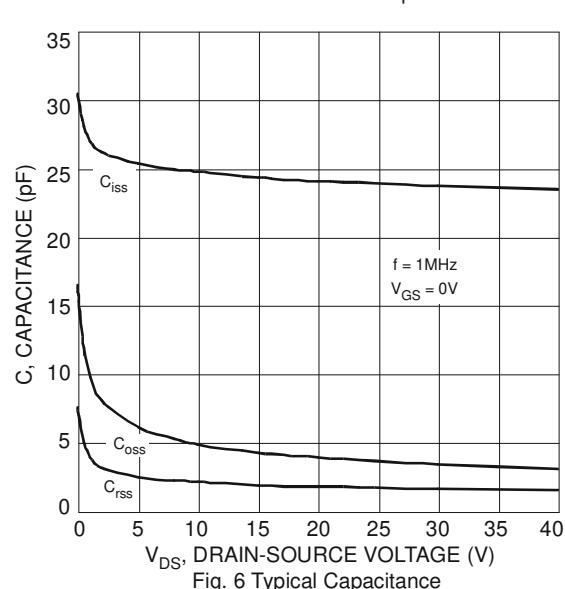
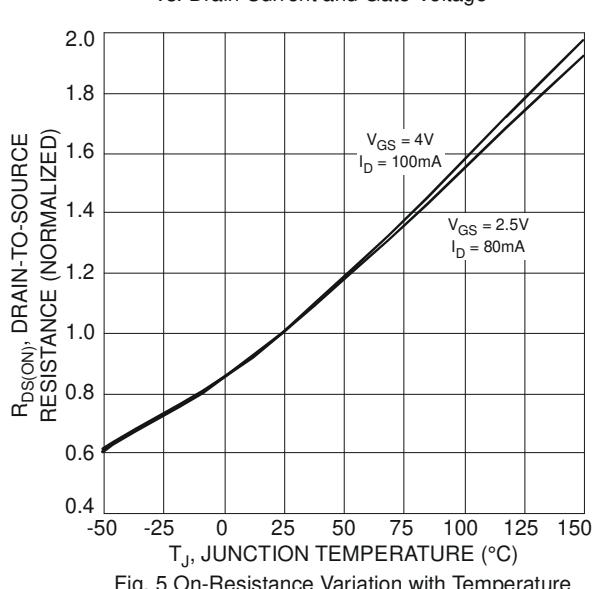
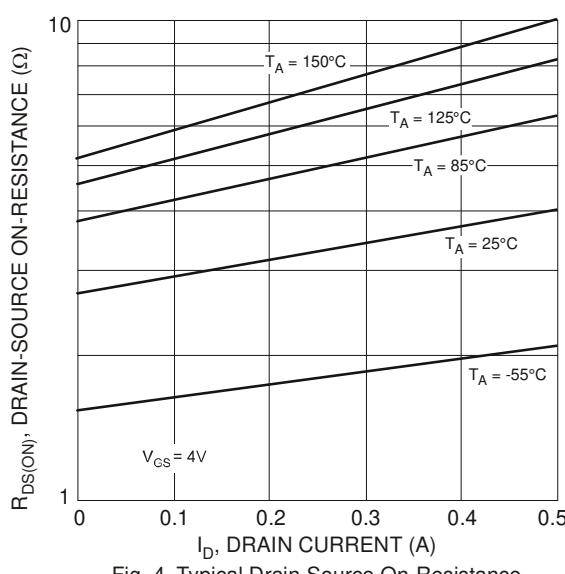
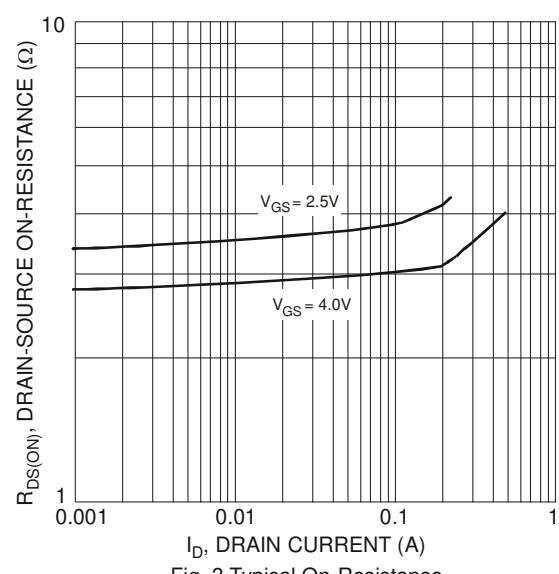
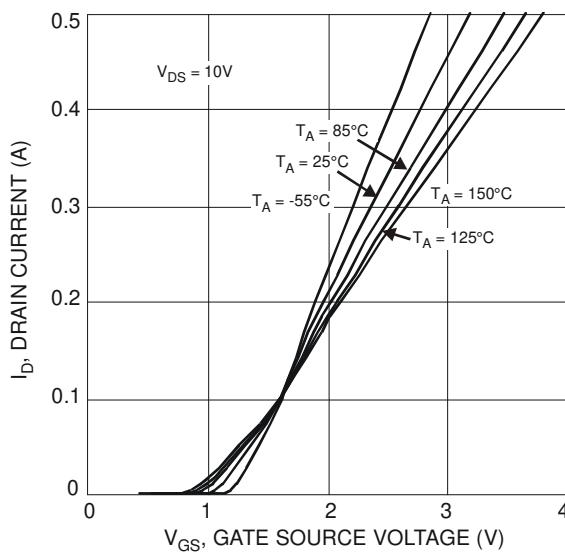
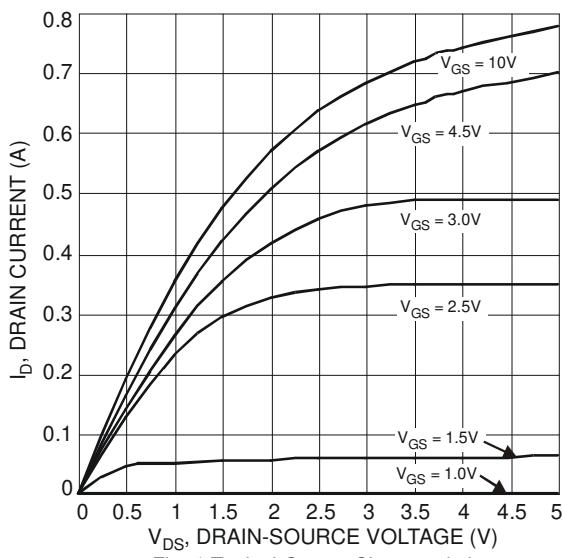
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	50	—	—	V	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	1	μA	$V_{DS} = 50\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	I_{GS}	—	—	1.0 5.0	μA	$V_{GS} = \pm 8\text{V}, V_{DS} = 0\text{V}$ $V_{GS} = \pm 12\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(TH)}$	0.7	0.8	1.0	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	3.1	4	Ω	$V_{GS} = 4\text{V}, I_D = 100\text{mA}$
		—	4	5		$V_{GS} = 2.5\text{V}, I_D = 80\text{mA}$
Forward Transconductance	g_{FS}	180	—	—	mS	$V_{DS} = 10\text{V}, I_D = 100\text{mA}, f = 1.0\text{KHz}$
Diode Forward Voltage	V_{SD}	—	0.70	1.3	V	$V_{GS} = 0\text{V}, I_S = 100\text{mA}$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{ISS}	—	25	—	pF	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Output Capacitance	C_{OSS}	—	5	—	pF	
Reverse Transfer Capacitance	C_{RSS}	—	2.1	—	pF	
Gate Resistance	R_G	—	500	—	Ω	$f = 1\text{MHz}, V_{GS} = 0\text{V}, V_{DS} = 0\text{V}$
Total Gate Charge ($V_{GS} = 4\text{V}$)	Q_G	—	295	—	pC	$V_{DS} = 10\text{V}, I_D = 100\text{mA}$
Total Gate Charge ($V_{GS} = 8\text{V}$)	Q_G	—	636	—	pC	
Gate-Source Charge	Q_{GS}	—	72	—	pC	
Gate-Drain Charge	Q_{GD}	—	18	—	pC	
Turn-On Delay Time	$t_{D(ON)}$	—	6.0	—	ns	$V_{DD} = 10\text{V}, V_{GS} = 4\text{V}, R_G = 25\Omega, I_D = 100\text{mA}$
Turn-On Rise Time	t_R	—	4.4	—	ns	
Turn-Off Delay Time	$t_{D(OFF)}$	—	23.4	—	ns	
Turn-Off Fall Time	t_F	—	11.0	—	ns	

Notes: 6. Device mounted on FR-4 PCB, with minimum recommended pad layout.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



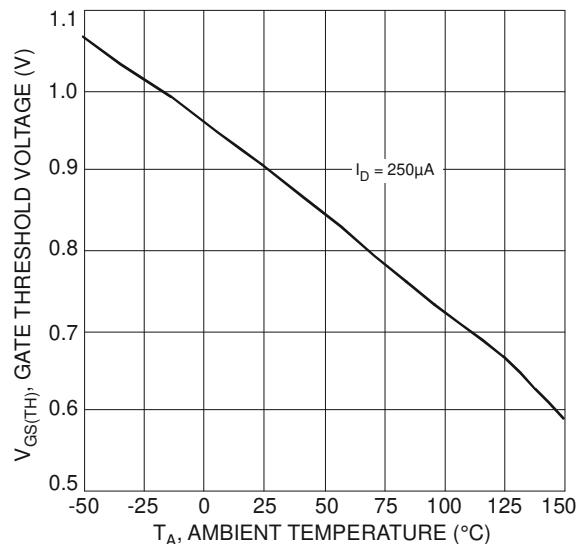


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

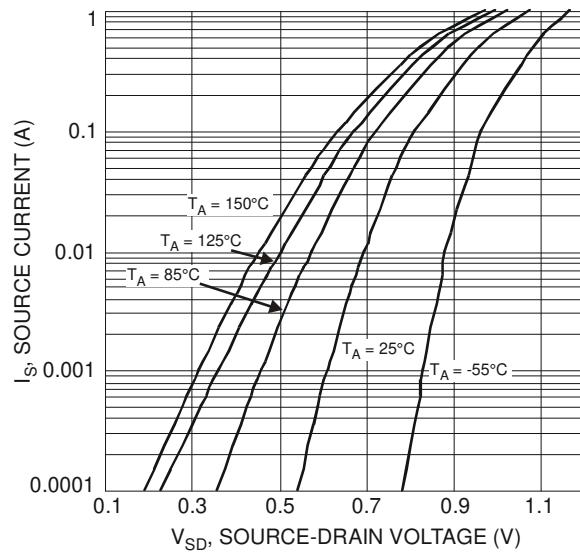


Fig. 8 Diode Forward Voltage vs. Current

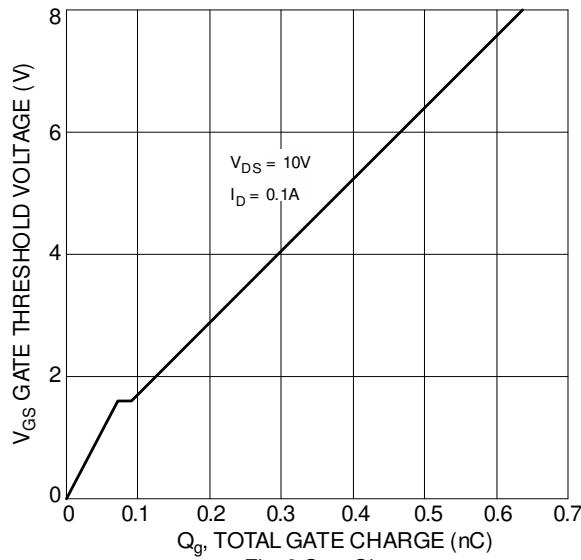


Fig. 9 Gate Charge

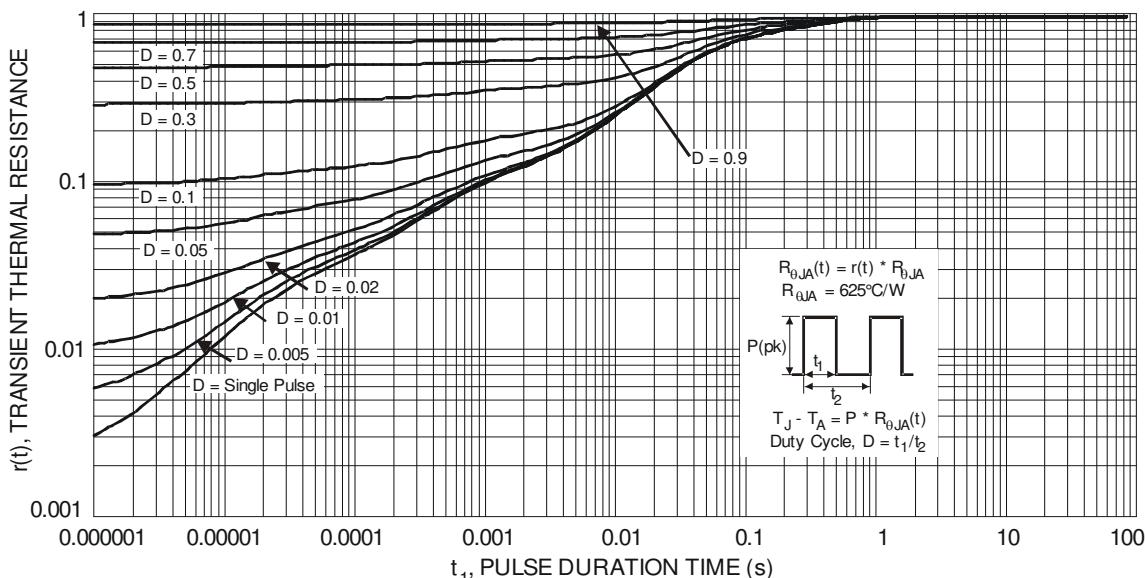
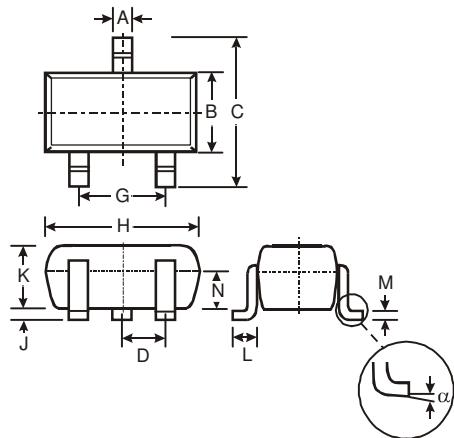


Fig. 10 Transient Thermal Response

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

SOT523



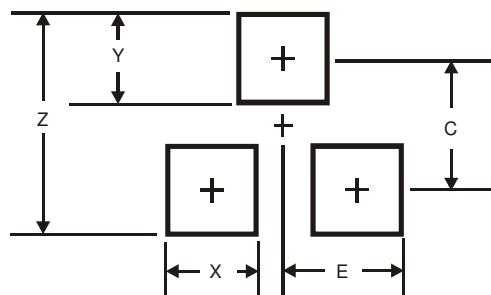
SOT523			
Dim	Min	Max	Typ
A	0.15	0.30	0.22
B	0.75	0.85	0.80
C	1.45	1.75	1.60
D	—	—	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
J	0.00	0.10	0.05
K	0.60	0.80	0.75
L	0.10	0.30	0.22
M	0.10	0.20	0.12
N	0.45	0.65	0.50
α	0°	8°	—

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

SOT523



Dimensions	Value (in mm)
Z	1.8
X	0.4
Y	0.51
C	1.3
E	0.7

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